

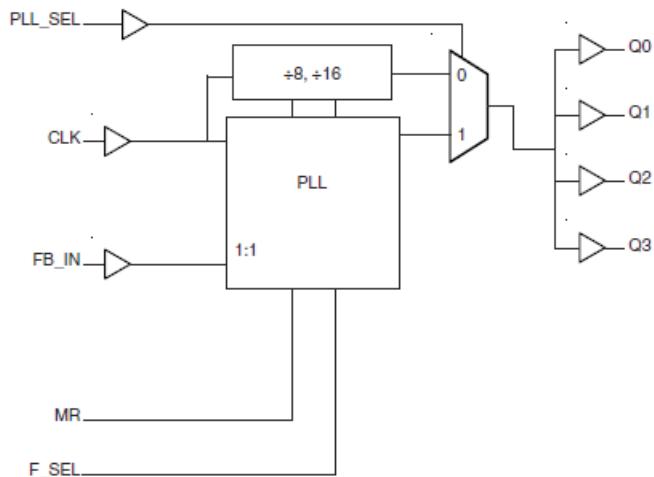
## GENERAL DESCRIPTION

The 86004I is a high performance 1:4 LVCMOS/LVTTL Clock Buffer. The 86004I has a fully integrated PLL and can be configured as zero delay buffer and has an input and output frequency range of 15.625MHz to 62.5MHz. The VCO operates at a frequency range of 250MHz to 500MHz. The external feedback allows the device to achieve “zero delay” between the input clock and the output clocks. The PLL\_SEL pin can be used to bypass the PLL for system test and debug purposes. In bypass mode, the reference clock is routed around the PLL and into the internal output divider.

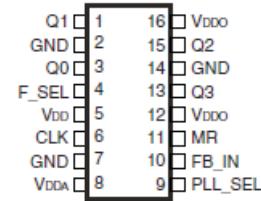
## FEATURES

- Four LVCMOS/LVTTL outputs, 7Ω typical output impedance
- Single LVCMOS/LVTTL clock input
- CLK accepts the following input levels: LVCMOS or LVTTL
- Output frequency range: 15.625MHz to 62.5MHz
- Input frequency range: 15.625MHz to 62.5MHz
- VCO range: 250MHz to 500MHz
- External feedback for “zero delay” clock regeneration with configurable frequencies
- Fully integrated PLL
- Cycle-to-cycle jitter: 75ps (maximum)
- Output skew: 65ps (maximum)
- Full 3.3V or 2.5V, or 3.3V core/2.5V output operating supply
- -40°C to 85° ambient operating temperature
- Available in lead-free RoHS compliant package

## BLOCK DIAGRAM



## PIN ASSIGNMENT



**86004I**  
16-Lead TSSOP  
4.4mm x 5.0mm x 0.925mm package body  
**G Package**  
Top View

**TABLE 1. PIN DESCRIPTIONS**

Number	Name	Type		Description
1, 3, 13, 15	Q1, Q0, Q3, Q2	Output		Clock outputs. 7 typical output impedance. LVCMOS/LVTTL interface levels.
2, 7, 14	GND	Power		Power supply ground.
4	F_SEL	Input	Pulldown	Frequency range select input. See Table 3A and 3B. LVCMOS/LVTTL interface levels.
5	V <sub>DD</sub>	Power		Core supply pin.
6	CLK	Input	Pulldown	LVCMOS/LVTTL clock input.
8	V <sub>DDA</sub>	Power		Analog supply pin.
9	PLL_SEL	Input	Pullup	Selects between the PLL and reference clock as input to the dividers. When LOW, selects the reference clock (PLL Bypass). When HIGH, selects PLL (PLL Enabled). LVCMOS/LVTTL interface levels.
10	FB_IN	Input	Pulldown	Feedback input to phase detector for regenerating clocks with “zero delay”. Connect to one of the outputs. LVCMOS/LVTTL interface levels.
11	MR	Input	Pulldown	Active HIGH Master Reset. When logic HIGH, the internal dividers are reset causing the outputs to go low. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS/LVTTL interface levels.
12, 16	V <sub>DDO</sub>	Power		Output supply pins.

NOTE: andrefer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

**TABLE 2. PIN CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ
C <sub>PD</sub>	Power Dissipation Capacitance (per output)	V <sub>DD</sub> , V <sub>DDA</sub> , V <sub>DDO</sub> = 3.465V			23	pF
		V <sub>DD</sub> , V <sub>DDA</sub> , V <sub>DDO</sub> = 2.625V			17	pF
R <sub>OUT</sub>	Output Impedance	3.3V ± 5%	5	7	12	Ω

**TABLE 3A. CONTROL INPUT FUNCTION TABLE, PLL\_SEL = 1**

Input	Input/Output Frequency Range (MHz)	
	Minimum	Maximum
0	31.25	62.5
1	15.625	31.25

**TABLE 3B. CONTROL INPUT FUNCTION TABLE, PLL\_SEL = 0**

Input	Output
0	Ref ÷8
1	Ref ÷16

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage, $V_{DD}$	4.6V
Inputs, $V_i$	-0.5V to $V_{DD} + 0.5$ V
Outputs, $V_o$	-0.5V to $V_{DDO} + 0.5$ V
Package Thermal Impedance, $\theta_{JA}$	89°C/W (0 lfpm)
Storage Temperature, $T_{STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 4A. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ\text{C}$  TO  $85^\circ\text{C}$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		3.135	3.3	$V_{DD}$	V
$V_{DDO}$	Output Supply Voltage		3.135	3.3	3.465	V
$I_{DD}$	Power Supply Current				98	mA
$I_{DDA}$	Analog Supply Current				22	mA
$I_{DDO}$	Output Supply Current				8	mA

TABLE 4B. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ\text{C}$  TO  $85^\circ\text{C}$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		3.135	3.3	V	V
$V_{DDO}$	Output Supply Voltage		2.375	2.5	2.625	V
$I_{DD}$	Power Supply Current				98	mA
$I_{DDA}$	Analog Supply Current				22	mA
$I_{DDO}$	Output Supply Current				8	mA

TABLE 4C. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ\text{C}$  TO  $85^\circ\text{C}$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		2.375	2.5	2.625	V
$V_{DDA}$	Analog Supply Voltage		2.375	2.5	V	V
$V_{DDO}$	Output Supply Voltage		2.375	2.5	2.625	V
$I_{DD}$	Power Supply Current				88	mA
$I_{DDA}$	Analog Supply Current				18	mA
$I_{DDO}$	Output Supply Current				6	mA

**TABLE 4D. LVC MOS / LVTTL DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$  OR  $2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage	$V_{DD} = 3.3V$	2		$V_{DD} + 0.3$	V
		$V_{DD} = 2.5V$	1.7		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage	$V_{DD} = 3.3V$	-0.3		0.8	V
		$V_{DD} = 2.5V$	-0.3		0.7	V
$I_{IH}$	Input High Current	$V_{DD} = V_{IN} = 3.465V$			150	$\mu A$
		$V_{DD} = V_{IN} = 3.465V$			5	$\mu A$
$I_{IL}$	Input Low Current	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			$\mu A$
		$V_{DD} = 3.465V, V_{IN} = 0V$	-150			$\mu A$
$V_{OH}$	Output High Voltage; NOTE 1	$V_{DDO} = 3.465V$	2.6			V
		$V_{DDO} = 2.625V$	1.8			V
$V_{OL}$	Output Low Voltage; NOTE 1	$V_{DDO} = 3.465V$ or $2.625V$			0.5	V

NOTE 1: Outputs terminated with 50W to  $V_{DDO}/2$ . See Parameter Measurement Information Section, Output Load Test Circuit diagrams.

**TABLE 5A. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency	$F_{SEL} = 0$	31.25		62.5	MHz
		$F_{SEL} = 1$	15.625		31.25	MHz
$tp_{LH}$	Propagation Delay, Low-to-High; NOTE 1	$PLL_{SEL} = 0V$ , Bypass Mode	4.1		6.1	ns
$t(\emptyset)$	Static Phase Offset; NOTE 2, 4	$PLL_{SEL} = 3.3V$	-500		500	ps
$tsk(o)$	Output Skew; NOTE 3, 4	$PLL_{SEL} = 0V$			65	ps
$t_{jit(cc)}$	Cycle-to-Cycle Jitter; NOTE 4				75	ps
$t_L$	PLL Lock Time				1	mS
$t_R / t_F$	Output Rise/Fall Time		0.4		1	ns
$odc$	Output Duty Cycle		49		51	%

All parameters measured at  $f_{MAX}$  unless noted otherwise.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from  $V_{DD}/2$  of the input crossing point to the output at  $V_{DDO}/2$ .

NOTE 2: Defined as the time difference between the input reference clock and the average feedback input signal when the PLL is locked and the input reference frequency is stable.

NOTE 3: Defined as skew between outputs at the same supply voltages and with equal load conditions.

Measured at  $V_{DDO}/2$ .

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

**TABLE 5B. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency	$F\_SEL = 0$	31.25		62.5	MHz
		$F\_SEL = 1$	15.625		31.25	MHz
$tp_{LH}$	Propagation Delay, Low-to-High; NOTE 1	PLL_SEL = 0V, Bypass Mode	4.25		6.25	ns
$t(\emptyset)$	Static Phase Offset; NOTE 2, 4	PLL_SEL = 2.5V	-500		500	ps
$tsk(o)$	Output Skew; NOTE 3, 4	PLL_SEL = 0V			65	ps
$tjit(cc)$	Cycle-to-Cycle Jitter; NOTE 4				75	ps
$t_L$	PLL Lock Time				1	mS
$t_R / t_F$	Output Rise/Fall Time		0.4		1	ns
odc	Output Duty Cycle		48		52	%

All parameters measured at  $f_{MAX}$  unless noted otherwise.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 Ifpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from  $V_{DD}/2$  of the input crossing point to the output at  $V_{DDO}/2$ .

NOTE 2: Defined as the time difference between the input reference clock and the average feedback input signal when the PLL is locked and the input reference frequency is stable.

NOTE 3: Defined as skew between outputs at the same supply voltages and with equal load conditions.

Measured at  $V_{DD}/2$ .

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

**TABLE 5C. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency	$F\_SEL = 0$	31.25		62.5	MHz
		$F\_SEL = 1$	15.625		31.25	MHz
$tp_{LH}$	Propagation Delay, Low-to-High; NOTE 1	PLL_SEL = 0V, Bypass Mode	4.5		6.5	ns
$t(\emptyset)$	Static Phase Offset; NOTE 2, 4	PLL_SEL = 2.5V	-500		500	ps
$tsk(o)$	Output Skew; NOTE 3, 4	PLL_SEL = 0V			65	ps
$tjit(cc)$	Cycle-to-Cycle Jitter; NOTE 4				75	ps
$t_L$	PLL Lock Time				1	mS
$t_R / t_F$	Output Rise/Fall Time		0.4		1	ns
odc	Output Duty Cycle		48		52	%

All parameters measured at  $f_{MAX}$  unless noted otherwise.

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 Ifpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from  $V_{DD}/2$  of the input crossing point to the output at  $V_{DDO}/2$ .

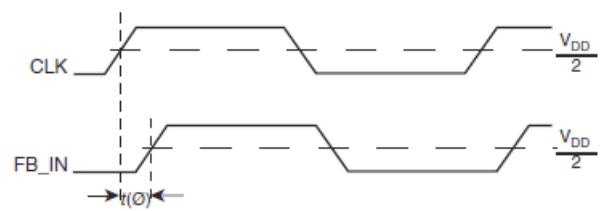
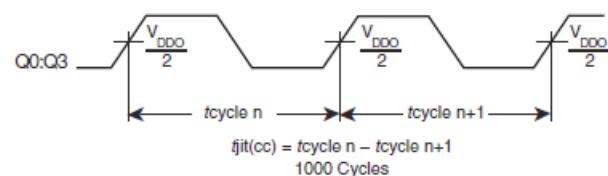
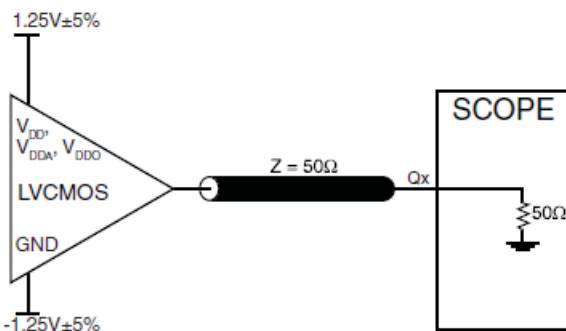
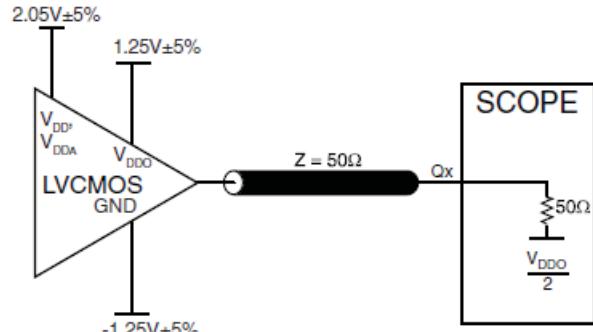
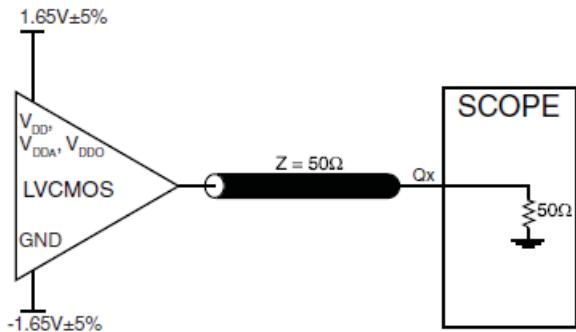
NOTE 2: Defined as the time difference between the input reference clock and the average feedback input signal when the PLL is locked and the input reference frequency is stable.

NOTE 3: Defined as skew between outputs at the same supply voltages and with equal load conditions.

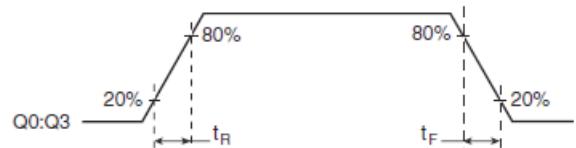
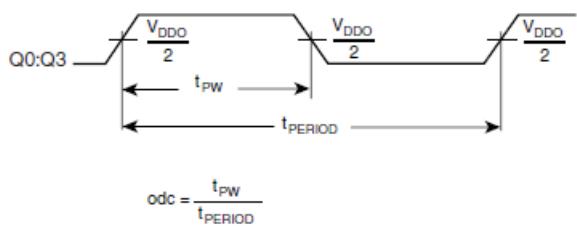
Measured at  $V_{DD}/2$ .

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

## PARAMETER MEASUREMENT INFORMATION

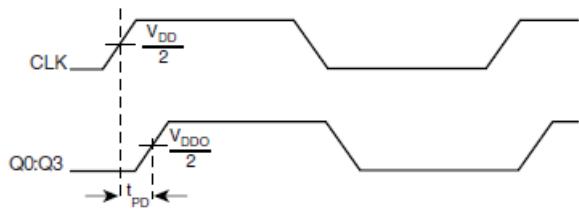


## PARAMETER MEASUREMENT INFORMATION, CONTINUED



OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD

OUTPUT RISE/FALL TIME



PROPAGATION DELAY

## APPLICATION INFORMATION

### POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 860041 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$ , and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and  $0.01\mu F$  bypass capacitors should be used for each pin. Figure 1 illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu F$  bypass capacitor be connected to the  $V_{DDA}$  pin.

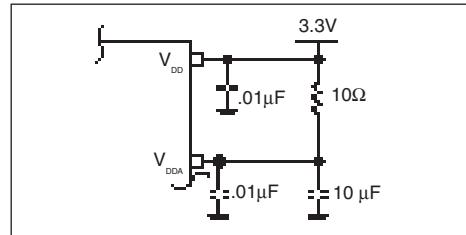


FIGURE 1. POWER SUPPLY FILTERING

### RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

#### INPUTS:

##### LVC MOS CONTROL PINS

All control pins have internal pullups or pulldowns; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

#### OUTPUTS:

##### LVC MOS OUTPUTS

All unused LVC MOS output can be left floating. We recommend that there is no trace attached.

### SCHEMATIC EXAMPLE

Figure 2 shows a schematic example of using an 860041. It is recommended to have one decouple capacitor per power pin. Each decoupling capacitor should be located as close as possible to the

power pin. The low pass filter  $R7$ ,  $C11$  and  $C16$  for clean analog supply should also be located as close to the  $V_{DDA}$  pin as possible.

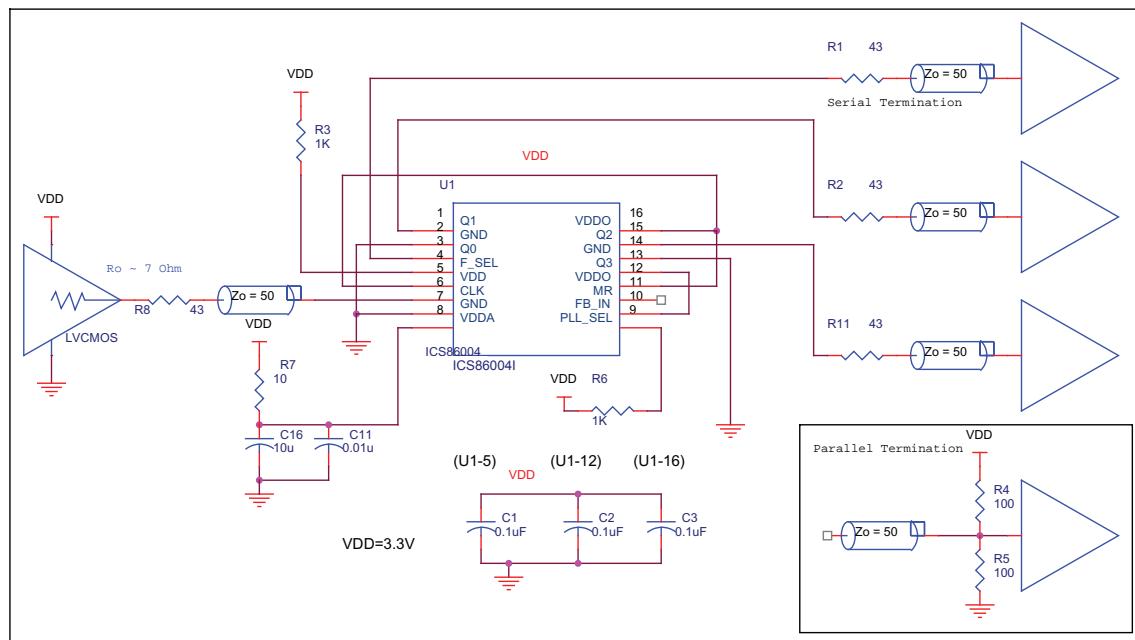


FIGURE 2. 860041 SCHEMATIC EXAMPLE

## RELIABILITY INFORMATION

TABLE 5.  $\theta_{JA}$  VS. AIR FLOW TABLE FOR 16 LEAD TSSOP

### $\theta_{JA}$ by Velocity (Linear Feet per Minute)

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	137.1°C/W	118.2°C/W	106.8°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	89.0°C/W	81.8°C/W	78.1°C/W

**NOTE:** Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

### TRANSISTOR COUNT

The transistor count for 86004I is: 2496

## PACKAGE OUTLINE - G SUFFIX 16 LEAD TSSOP

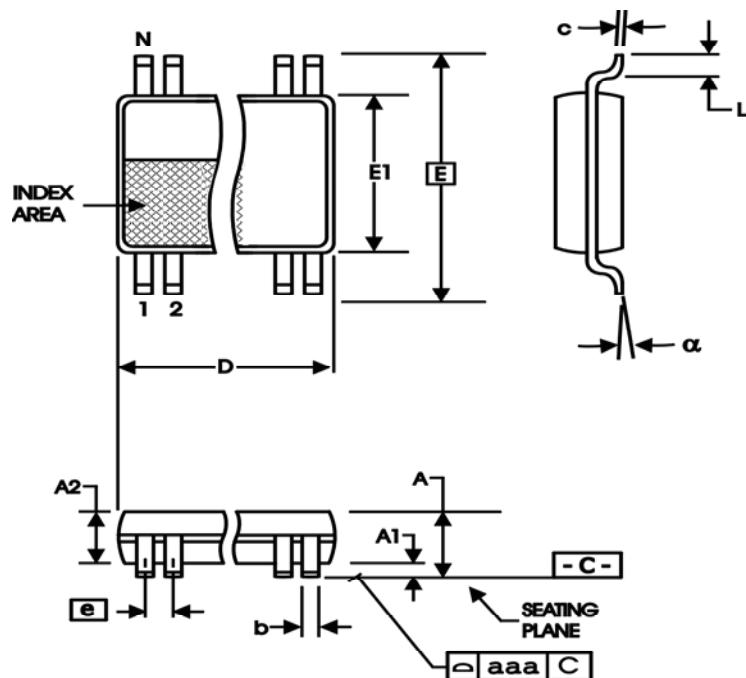


TABLE 6. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	16	
A	--	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 BASIC	
E1	4.30	4.50
e	0.65 BASIC	
L	0.45	0.75
alpha	0°	8°
aaa	--	0.10

Reference Document: JEDEC Publication 95, MO-153

**TABLE 7. ORDERING INFORMATION**

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
86004BGILF	86004BIL	16 Lead "Lead-Free" TSSOP	Tube	-40°C to 85°C
86004BGILFT	86004BIL	16 Lead "Lead-Free" TSSOP	Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

## REVISION HISTORY SHEET

Rev	Table	Page	Description of Change	Date
A	5A - 5C T7	4 - 5 11	AC Tables - added thermal note and corrected NOTE 1. Ordering Information Table - added LF marking and deleted "ICS" prefix from Part/Order Number column. Updated Header/Footer.	2/24/10
A	T7	11	Ordering Information - removed leaded devices. Updated data sheet format.	7/10/15



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